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| PATENT ASSIGNMENT COVER SHEET |
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| SUBMISSION TYPE: | NEW ASSIGNMENT |
| NATURE OF CONVEYANCE: | ASSIGNMENT |
| CONVEYING PARTY DATA | |
| Name | Execution Date |
| MR JUN HU | 10/02/2018 |
| MR FEI WANG | 10/02/2018 |
| MR MENGYU PAN | 10/02/2018 |
| MR ZHIYUN LUO | 10/02/2018 |
| RECEIVING PARTY DATA | |
| Name: | HUNTECK SEMICONDUCTOR (SHANGHAI), LTD. |
| Street Address: | 560 SHENGXIA ROAD |
| Internal Address: | SUITE 920C-7 |
| City: | SHANGHAI |
| State/Country: | CHINA |
| Postal Code: | 201210 |
| PROPERTY NUMBERS Total: 2 | |
| Property Type | Number |
| Patent Number: | 10038089 |
| Application Number: | 16048285 |
| CORRESPONDENCE DATA | |
| Fax Number: | |
| <i>Correspondence will be sent to the e-mail address first; if that is unsuccessful, it will be sent using a fax number, if provided; if that is unsuccessful, it will be sent via US Mail.</i> | |
| Phone: | 6509490418 |
| Email: | boinlin@gmail.com |
| Correspondent Name: | BO-IN LIN |
| Address Line 1: | 13445 MANDOLI DRIVE |
| Address Line 4: | LOS ALTOS HILLS, CALIFORNIA 94022 |
| ATTORNEY DOCKET NUMBER: | HTC-1501 |
| NAME OF SUBMITTER: | BO-IN LIN |
| SIGNATURE: | /Bo-In Lin/ |
| DATE SIGNED: | 11/08/2018 |
| Total Attachments: 4 | |

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ASSIGNMENT

INVENTOR AND CITY Whereas, I, Jun Hu of 781 Acacia Avenue
San Bruno, California 94066

have invented:

TITLE: SGT MOSFET WITH ADJUSTABLE CRSS AND CISS

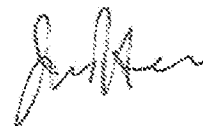
DATE INVENTOR and executed a United States patent application therefor
SIGNED THE on October 22, 2015;
DECLARATION

Whereas, Hunteck Semiconductor (Shanghai), Ltd., a Chinese Company, having its registered address at 560 Shengxia Road Suit 902C-7, Shanghai, China 201210 (hereinafter called HUNTECK), desires to acquire the entire right, title and interest of said application and invention, and to any United States and foreign patents to be obtained therefor;

Now therefore, for a valuable consideration, receipt whereof is hereby acknowledged, I, the above named, hereby sell, assign, and transfer to HUNTECK, its successors and assigns, the entire right, title and interest in the said application and invention therein disclosed for the United States and foreign countries, and all rights of priority resulting from the filing said United States application, and I request the Commissioner of Patents to issue any Letters Patent granted upon the inventions set forth in said application to HUNTECK its successors and assigns; and I hereby agree that HUNTECK may apply for foreign Letters Patent on said invention and I will execute all papers necessary in connection with the United States and foreign applications when called upon to do so by

CITY AND Signed and Sealed at San Bruno, California

DATE on October 2, 2018.



SIGNATURE OF INVENTOR

ASSIGNMENT

INVENTOR Whereas, I, Fei Wang of 1473 Shaffer Drive
AND CITY San Jose, California 95132

have invented:

TITLE: SGT MOSFET WITH ADJUSTABLE CRSS AND CISS

DATE INVENTOR and executed a United States patent application therefor
SIGNED THE
DECLARATION on October 22, 2015;

Whereas, **Hunteck Semiconductor (Shanghai), Ltd.**, a Chinese Company, having its registered address at 560 Shengxia Road Suit 902C-7, Shanghai, China 201210 (hereinafter called **HUNTECK**), desires to acquire the entire right, title and interest of said application and invention, and to any United States and foreign patents to be obtained therefor;

Now therefore, for a valuable consideration, receipt whereof is hereby acknowledged, I, the above named, hereby sell, assign, and transfer to **HUNTECK**, its successors and assigns, the entire right, title and interest in the said application and invention therein disclosed for the United States and foreign countries, and all rights of priority resulting from the filing said United States application, and I request the Commissioner of Patents to issue any Letters Patent granted upon the inventions set forth in said application to **HUNTECK** its successors and assigns; and I hereby agree that **HUNTECK** may apply for foreign Letters Patent on said invention and I will execute all papers necessary in connection with the United States and foreign applications when called upon to do so by

CITY AND Signed and Sealed at San Jose, California

DATE on October 2, 2018.



SIGNATURE OF INVENTOR

ASSIGNMENT

INVENTOR AND CITY Whereas, I, Mengyu Pan of Suit 22-2021, 368 Zhangjiang Road
Shanghai, China 201203

have invented:

TITLE: SGT MOSFET WITH ADJUSTABLE CRSS AND CISS

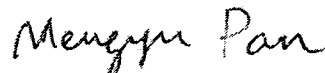
DATE INVENTOR and executed a United States patent application therefor
SIGNED THE
DECLARATION on October 22, 2015;

Whereas, Hunteck Semiconductor (Shanghai), Ltd., a Chinese Company, having its registered address at 560 Shengxia Road Suit 902C-7, Shanghai, China 201210 (hereinafter called HUNTECK), desires to acquire the entire right, title and interest of said application and invention, and to any United States and foreign patents to be obtained therefor;

Now therefore, for a valuable consideration, receipt whereof is hereby acknowledged, I, the above named, hereby sell, assign, and transfer to HUNTECK, its successors and assigns, the entire right, title and interest in the said application and invention therein disclosed for the United States and foreign countries, and all rights of priority resulting from the filing said United States application, and I request the Commissioner of Patents to issue any Letters Patent granted upon the inventions set forth in said application to HUNTECK its successors and assigns; and I hereby agree that HUNTECK may apply for foreign Letters Patent on said invention and I will execute all papers necessary in connection with the United States and foreign applications when called upon to do so by

CITY AND Signed and Sealed at San Jose, California

DATE on October 2, 2018.



SIGNATURE OF INVENTOR

ASSIGNMENT

INVENTOR AND CITY Whereas, I, **Zhiyun Luo** of 1473 Shaffer Drive
San Jose, California 95132

have invented:

TITLE: **SGT MOSFET WITH ADJUSTABLE CRSS AND CISS**

DATE INVENTOR and executed a United States patent application therefor
SIGNED THE
DECLARATION on October 22, 2015;

Whereas, **Hunteck Semiconductor (Shanghai), Ltd.**, a Chinese Company, having its registered address at 560 Shengxia Road Suit 902C-7, Shanghai, China 201210 (hereinafter called **HUNTECK**), desires to acquire the entire right, title and interest of said application and invention, and to any United States and foreign patents to be obtained therefor;

Now therefore, for a valuable consideration, receipt whereof is hereby acknowledged, I, the above named, hereby sell, assign, and transfer to **HUNTECK**, its successors and assigns, the entire right, title and interest in the said application and invention therein disclosed for the United States and foreign countries, and all rights of priority resulting from the filing said United States application, and I request the Commissioner of Patents to issue any Letters Patent granted upon the inventions set forth in said application to **HUNTECK** its successors and assigns; and I hereby agree that **HUNTECK** may apply for foreign Letters Patent on said invention and I will execute all papers necessary in connection with the United States and foreign applications when called upon to do so by

CITY AND Signed and Sealed at San Jose, California

DATE on October 2, 2018.


SIGNATURE OF INVENTOR